



AH1899B

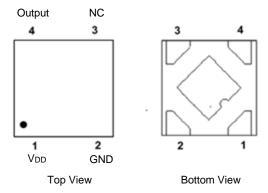
ULTRA LOW-VOLTAGE HIGH-SENSITIVITY MICROPOWER OMNIPOLAR HALL-EFFECT SWITCH

Description

The AH1899B is a high-sensitivity micropower, Omnipolar Hall-effect switch IC with internal pullup and pulldown capability. Designed for portable and battery-powered equipment, such as cellular phones and portable PCs, the average supply current is only 0.95µA at 1.2V and 1.1µA at 1.8V. To support portable equipment, the AH1899B can operate over the supply range of 1.1V to 2.0V and uses a hibernating clocking system to minimize the power consumption. To minimize PCB space, the AH1899B is available in a small low-profile X2-DFN1010-4 (Type B) package.

The output is activated with either a north or south pole of sufficient magnetic field strength. When the magnetic flux density (B) perpendicular to the package is larger than the operate point (Bop), the output is turned on (pulled low). The output is turned off when B becomes lower than the release point (BRP). The output will remain off when there is no magnetic field.

Pin Assignments



X2-DFN1010-4 (Type B)

Features

- Omnipolar Operation (North or South Pole)
- Supply Voltage of 1.1V to 2.0V
- Micropower Operation
- Chopper Stabilized Design Provides:
 - Superior Temperature Stability
 - Minimal Switch Point Drift
 - Enhanced Immunity to Physical Stress
- No External Pullup Resistors Required
- · Good RF Noise Immunity
- -40°C to +85°C Operating Temperature
- Small Low-Profile X2-DFN1010-4 (Type B) Package
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

Applications

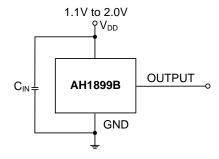
- Cover or display switches in portable PCs
- Open and close detection for cellular phones
- Holster or cover detection for cellular phones and tablet PCs
- Digital still, video cameras, and handheld gaming consoles
- Contactless switches

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



Typical Applications Circuit



Note: 4. C_{IN} is for power stabilization and to strengthen the noise immunity. The recommended capacitance is 10nF to 100nF.

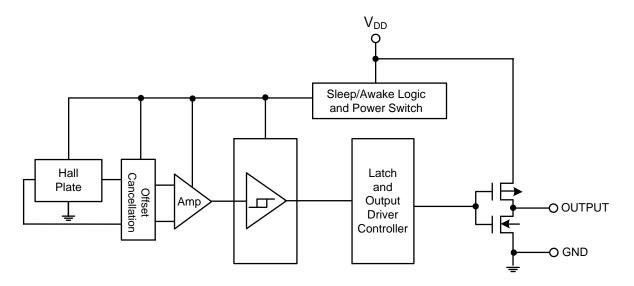
Pin Descriptions

Package: X2-DFN1010-4 (Type B)

Pin Number	Pin Name	Function
1	V _{DD}	Power Supply Input
2	GND	Ground Pin
3	NC	No Connection (Note 5)
4	OUTPUT	Output Pin

Note: 5. NC is the No Connection pin and is not connected internally. This pin can be left open or tied to ground.

Functional Block Diagram





Absolute Maximum Ratings (Note 6) (@TA = +25°C, unless otherwise specified.)

Symbol	Parameter		Rating	Unit
V _{DD}	Supply Voltage (Note 7)		2.2	V
VDD_REV	Reverse Supply Voltage		-0.3	V
Іоитрит	Output Current (Source and Sink)		3	mA
В	Magnetic Flux Density		Unlimited	
PD	Package Power Dissipation X2-DFN1010-4 (Type B)		230	mW
Ts	Storage Temperature Range		-65 to +150	°C
TJ	Maximum Junction Temperature		+150	°C
ESD HBM	Human Body Model (HMB) ESD Capability		8	kV

Notes:

- 6. Stresses greater than those listed under *Absolute Maximum Ratings* can cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to *Absolute Maximum Ratings* for extended periods can affect device reliability.
- 7. The absolute maximum V_{DD} of 2.2V is a transient stress rating and is not meant as a functional operating condition. It is not recommended to operate the device at the absolute maximum rated conditions for any period of time.

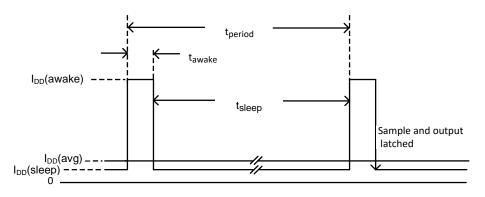
Recommended Operating Conditions (@TA = +25°C, unless otherwise specified.)

Symbol	Parameter	Conditions	Rating	Unit
V _{DD}	Supply Voltage	Operating	1.1 to 2	V
T _A	Operating Temperature Range	Operating	-40 to +85	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{OL}	Output Low Voltage (On)	$I_{OUT} = 0.5 \text{mA}, V_{DD} = 1.2 \text{V}$	_	0.1	0.2	V
V _{OH}	Output High Voltage (Off)	$I_{OUT} = 0.5 \text{mA}, V_{DD} = 1.2 \text{V}$	V _{DD} -0.2	V _{DD} -0.1	_	V
l(oweke)		During Awake Period, V _{DD} = 1.2V	_	0.55	1.1	mA
IDD(awake)	DD(awake) Supply Current	During Awake Period, V _{DD} = 1.8V	_	0.68	1.4	mA
l(alaan)		During <i>Sleep</i> Period, V _{DD} = 1.2V	_	0.29	0.6	μA
I _{DD} (sleep)		During <i>Sleep</i> Period, V _{DD} = 1.8V	_	0.35	0.7	μA
l(o)(a)	Average Supply Current	$T_A = +25^{\circ}C, V_{DD} = 1.2V$	_	0.95	1.8	μA
I _{DD} (avg)	Average Supply Current	$T_A = +25^{\circ}C, V_{DD} = 1.8V$	_	1.1	2.2	μA
t _{awake}	Awake Time	$T_A = +25^{\circ}C$, $V_{DD} = 1.2V$ (Note 8)	_	45	90	μs
tperiod	Period	$T_A = +25^{\circ}C$, $V_{DD} = 1.2V$ (Note 8)	_	45	90	ms
D.C.	Duty Cycle	_	_	0.1	_	%

Note: 8. When power is initially turned on, the operating V_{DD} (1.1V to 2.0V) must be applied to guarantee the output sampling. The output state is valid after the second operating cycle (typical 90ms).

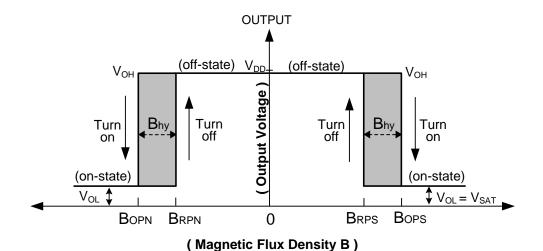




Magnetic Characteristics (T_A = +25°C, V_{DD} = 1.2V, unless otherwise specified)

(1mT = 10 Gauss)

Symbol	Characteristics	Min	Тур	Max	Unit
Bops (South Pole to Part Marking Side)	Operation Point -	20	30	40	
B _{OPN} (North Pole to Part Marking Side)		-40	-30	-20	
B _{RPS} (South Pole to Part Marking Side)	Release Point -	10	20	30	Gauss
B _{RPN} (North Pole to Part Marking Side)		-30	-20	-10	
B _{HY} (B _{OPX} - B _{RPX})	Hysteresis	_	10	_	



S

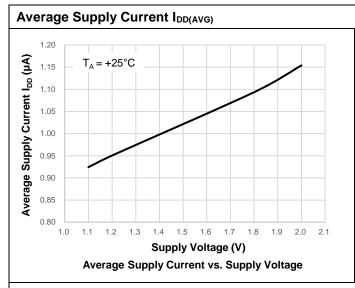
↑↑↑↑ Part mark

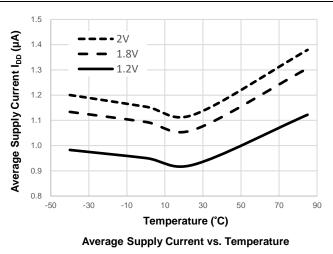
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X2-DFN1010-4 (Type B)

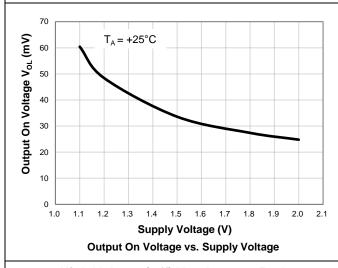


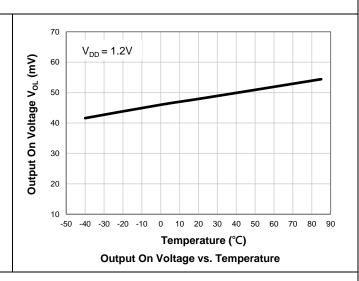
Typical Operating Characteristics



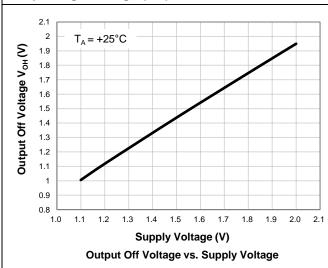


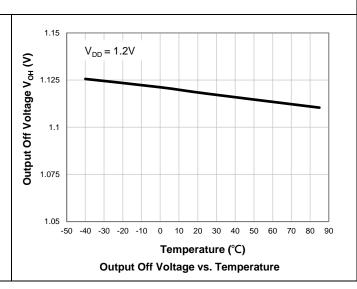
Output Low Voltage (On) Vol, Iout = 0.5mA





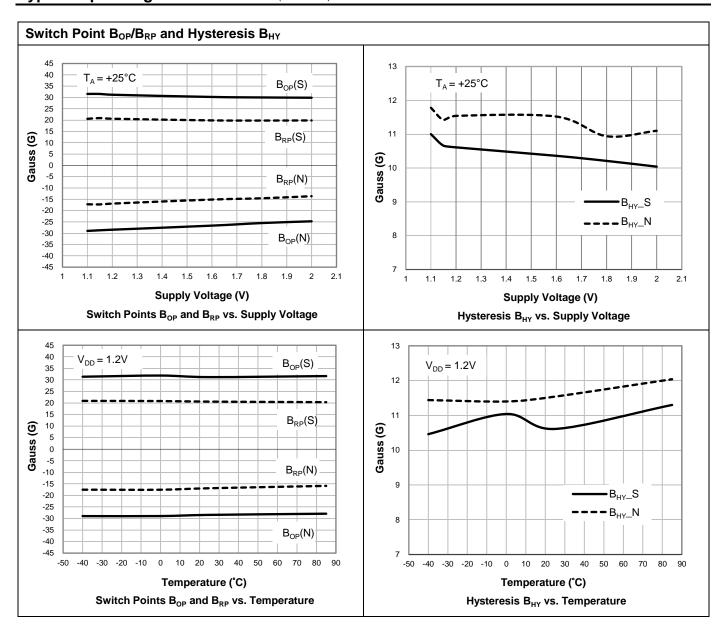
Output High Voltage (Off) V_{OH} , $I_{OUT} = -0.5$ mA





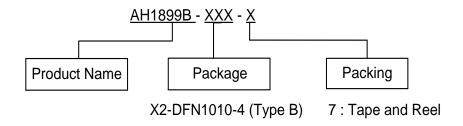


Typical Operating Characteristics (continued)





Ordering Information



Part Number	Part Number Suffix	Backago Codo	Package	Pac	king
Fait Number	Part Number Sumx	per Suffix Package Code Pac	Раскаде	Qty.	Carrier
AH1899B-FS4-7	-7	FS4	X2-DFN1010-4 (Type B)	5000	7" Tape and Reel

Marking Information

Package Type: X2-DFN1010-4 (Type B)

(Top View)

<u>XX</u> <u>Y W X</u> XX: Identification Code

Y: Year: 0 to 9 (ex: 3 = 2023)

W: Week: A to Z: week 1 to 26;
a to z: week 27 to 52; z represents
week 52 and 53

X: Internal Code

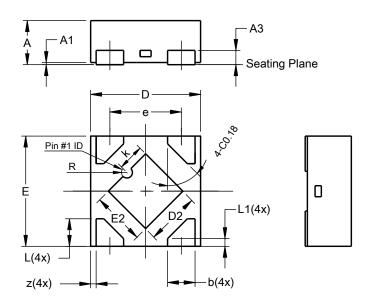
Part Number	Package	Identification Code
AH1899B-FS4-7	X2-DFN1010-4 (Type B)	CY



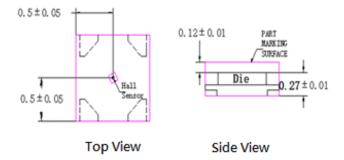
Package Outline Dimensions (All dimensions in mm.)

Please see http://www.diodes.com/package-outlines.html for the latest version.

X2-DFN1010-4 (Type B)



X2-	X2-DFN1010-4 (Type B)					
Dim	Min	Max	Тур			
Α	-	0.40	0.39			
A1	0.00	0.05	0.02			
A3	-	-	0.13			
b	0.20	0.30	0.25			
D	0.95	1.05	1.00			
D2	0.43	0.53	0.48			
E	0.95	1.05	1.00			
E2	0.43	0.53	0.48			
е	-	-	0.65			
k	0.19	0.29	0.24			
L	0.20	0.30	0.25			
L1	0.02	0.12	0.07			
R	0.02	0.08	0.05			
Z	-	-	0.050			
All Dimensions in mm						



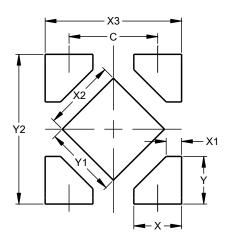
Sensor Location



Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

X2-DFN1010-4 (Type B)



Dimensions	Value (in mm)
С	0.650
Х	0.350
X1	0.112
X2	0.530
Х3	1.00
Y	0.350
Y1	0.530
Y2	1.100

Mechanical Data

- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu over Copper Leads, Solderable per MIL-STD-202, Method 208 @4
- Weight: 0.001 grams (Approximate)



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AH1899B 10 of 10
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